

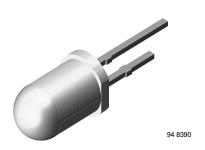
Vishay Semiconductors

HALOGEN FREE

GREEN

(5-2008)

Infrared Emitting Diode, 950 nm, GaAs



www.vishay.com

DESCRIPTION

TSUS5400 is an infrared, 950 nm emitting diode in GaAs technology molded in a blue-gray tinted plastic package.

FEATURES

Package type: leaded
Package form: T-1¾
Dimensions (in mm): Ø 5
Leads with stand-off

- Leads With Stand-On

• Peak wavelength: $\lambda_p = 950 \text{ nm}$

High reliability

• Angle of half intensity: $\varphi = \pm 22^{\circ}$

· Low forward voltage

• Suitable for high pulse current operation

· Good spectral matching with Si photodetectors

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Infrared remote control and free air transmission systems with low forward voltage and small package requirements
- · Emitter in transmissive sensors
- · Emitter in reflective sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (°)	λ _p (nm)	t _r (ns)	
TSUS5400	14	± 22	950	800	
TSUS5401	17	± 22	950	800	
TSUS5402	20	± 22	950	800	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
TSUS5400	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
TSUS5401	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾			
TSUS5402	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-13/4			

Note

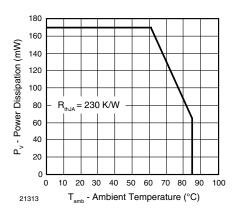
MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL VALUE		UNIT		
Reverse voltage		V _R	5	V		
Forward current		I _F	150	mA		
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	300	mA		
Surge forward current	t _p = 100 μs	I _{FSM}	2.5	Α		
Power dissipation		P _V	170	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	- 40 to + 85	°C		
Storage temperature range		T _{stg}	- 40 to + 100	°C		
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W		



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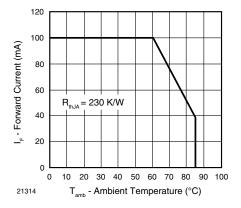


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL MIN. TYP. MAX		MAX.	UNIT		
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.3	1.7	V	
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.3		mV/K	
Reverse current	V _R = 5 V	I _R			100	μΑ	
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C _j		30		pF	
Temperature coefficient of ϕ_e	I _F = 20 mA	TKφ _e		- 0.8		%/K	
Angle of half intensity		φ		± 22		0	
Peak wavelength	I _F = 100 mA	λρ		950		nm	
Spectral bandwidth	I _F = 100 mA	Δλ		50		nm	
Temperature coefficient of λ_p	I _F = 100 mA	TKλ _p		0.2		nm/K	
Disc. No.	I _F = 100 mA	t _r		800		ns	
Rise time	I _F = 1.5 A	t _r		400		ns	
Fall time	I _F = 100 mA	t _f		800		ns	
Fall time	I _F = 1.5 A	t _f		400		ns	
Virtual source diameter		d		2.9		mm	

TYPE DEDICATED CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 1.5 A, t _p = 100 μs	TSUS5400	V _F		2.2	3.4	V
Forward voltage		TSUS5401	V_{F}		2.2	3.4	V
		TSUS5402	V_{F}		2.2	2 3.4 2 3.4 2 2.7 4 35 ml 7 35 ml 0 35 ml 60 ml 60 ml	V
		TSUS5400	l _e	7	14	35	mW/sr
	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSUS5401	l _e	10	17	35	mW/sr
Dadient intensity		TSUS5402	l _e	15	20	35	mW/sr
Radiant intensity		TSUS5400	l _e	60	140		mW/sr
	$I_F = 1.5 \text{ A}, t_p = 100 \mu \text{s}$	TSUS5401	l _e	85	160		mW/sr
		TSUS5402	l _e	120	190		mW/sr
		TSUS5400	φ _e		13		mW
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSUS5401	фе		14		mW
		TSUS5402	φ _e		15		mW



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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

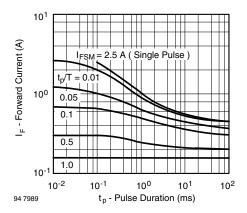


Fig. 3 - Pulse Forward Current vs. Pulse Duration

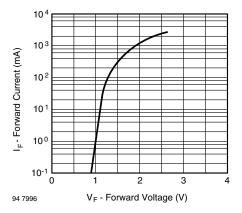


Fig. 4 - Forward Current vs. Forward Voltage

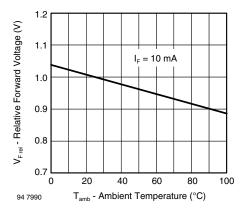


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

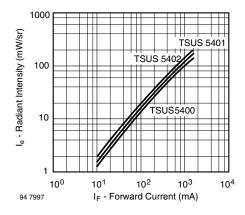


Fig. 6 - Radiant Intensity vs. Forward Current

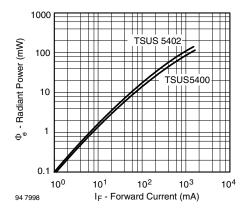


Fig. 7 - Radiant Power vs. Forward Current

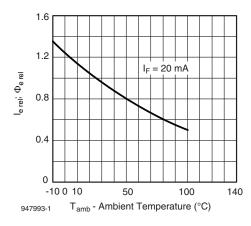


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature



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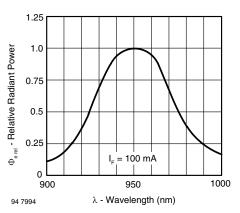


Fig. 9 - Relative Radiant Power vs. Wavelength

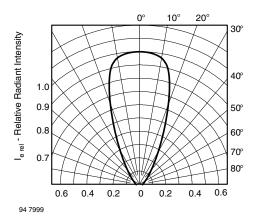
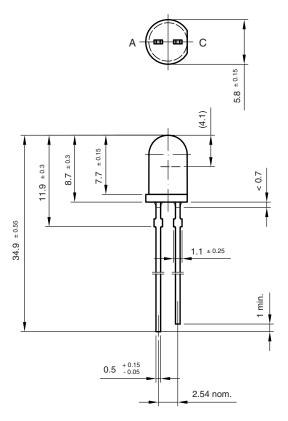
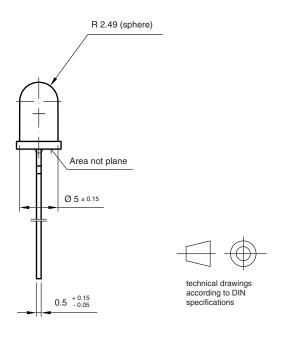


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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